

OPA1671 13-MHz, Low-Noise, Rail-to-Rail, Audio Operational Amplifier



1 Features

- Low noise:
 - 4 nV/ $\sqrt{\text{Hz}}$ at 10 kHz
 - 4.7 fA/ $\sqrt{\text{Hz}}$ at 1 kHz
- Low distortion: –109 dB (0.00035%)
- Wide gain bandwidth: 13 MHz
- Rail-to-rail input and output
- Low supply-voltage operation: 1.7 V to 5.5 V
- Low input capacitance
 - Differential: 6 pF
 - Common-mode: 2.5 pF
- Low input-bias current: 10 pA
- Low power supply current: 940 μA
- Industry-standard packages: SC-70 and SOT-23

2 Applications

- Microphone preamplifier
- Auxiliary line input and output
- Active filter circuit
- Transimpedance amplifier
- Voltage buffer

3 Description

The OPA1671 is a wide-bandwidth, low-noise, low-distortion, audio operational amplifier that provides rail-to-rail input and output operation. This device offers an excellent combination of low voltage noise, current noise, and input capacitance, allowing the device to deliver high performance in a wide array of audio and industrial applications. The unique internal topology of the OPA1671 delivers very low distortion (–109 dB), while only consuming 940 μA of power supply current. The wide bandwidth (13 MHz) and high slew rate (5 V/ μs) of OPA1671 makes this device an excellent choice for high gain audio and industrial signal conditioning.

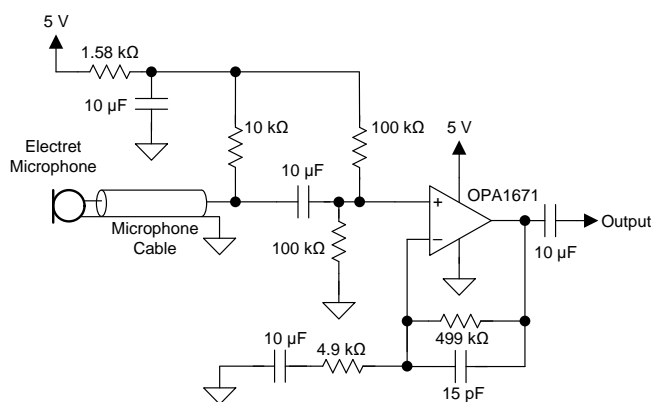
The OPA1671 is available in the SC-70 and SOT-23 packages and is specified over the industrial temperature range (–40°C to +125°C).

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)
OPA1671	SC-70 (5)	2.00 mm x 1.25 mm
	SOT-23 (5)	2.90 mm x 1.60 mm

(1) For all available packages, see the package option addendum at the end of the data sheet.

Electret Microphone Preamplifier



OPA1671 Voltage Noise Density

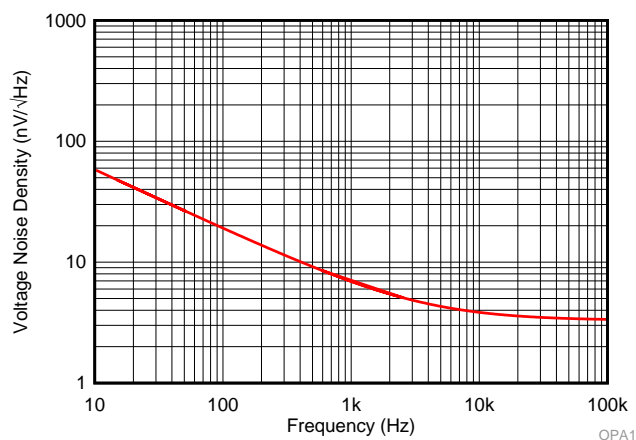


Table of Contents

1 Features	1	8 Application and Implementation	15
2 Applications	1	8.1 Application Information.....	15
3 Description	1	8.2 Typical Application	17
4 Revision History	2	9 Power Supply Recommendations	19
5 Pin Configuration and Functions	3	10 Layout	19
6 Specifications	4	10.1 Layout Guidelines	19
6.1 Absolute Maximum Ratings	4	10.2 Layout Example	19
6.2 ESD Ratings.....	4	11 Device and Documentation Support	20
6.3 Recommended Operating Conditions.....	4	11.1 Device Support.....	20
6.4 Thermal Information	4	11.2 Documentation Support	20
6.5 Electrical Characteristics.....	5	11.3 Receiving Notification of Documentation Updates	20
6.6 Typical Characteristics	7	11.4 Community Resources.....	20
7 Detailed Description	12	11.5 Trademarks	21
7.1 Overview	12	11.6 Electrostatic Discharge Caution.....	21
7.2 Functional Block Diagram	12	11.7 Glossary	21
7.3 Feature Description.....	13	12 Mechanical, Packaging, and Orderable	
7.4 Device Functional Modes.....	14	Information	21

4 Revision History

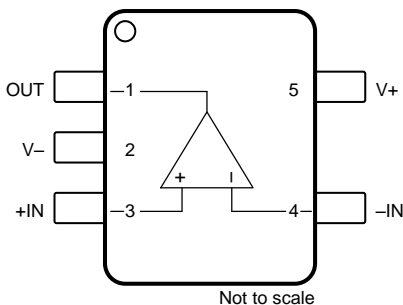
NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision A (January 2019) to Revision B	Page
• Added SOT-23 (DBV) package and associated content to data sheet	1
• Added input offset voltage specification for $V_{CM} = (V+), (V-)$	5

Changes from Original (November 2018) to Revision A	Page
• Changed from advanced information (preview) to production data (active).....	1

5 Pin Configuration and Functions

**DBV and DCK Packages
5-Pin SOT-23 and SC-70
Top View**



Pin Functions

PIN		I/O	DESCRIPTION
NAME	NO.		
-IN	4	I	Inverting input
+IN	3	I	Noninverting input
OUT	1	O	Output
V-	2	—	Negative (lowest) power supply
V+	5	—	Positive (highest) power supply

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

	MIN	MAX	UNIT
Supply voltage, $V_S = (V+) - (V-)$		6	V
Input voltage	(V-) -0.3	(V+) +0.3	V
Output short-circuit ⁽²⁾	Continuous		
Operating temperature, T_A	-55	150	°C
Storage temperature, T_{stg}	-65	150	°C

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) Short-circuit to ground, one amplifier per package.

6.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	2000	V
		Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾	500	

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

	MIN	NOM	MAX	UNIT
Supply voltage, $V_S = (V+) - (V-)$	1.7 (± 0.85)		5.5 (± 2.75)	V
Specified temperature, T_A	-40		125	°C

6.4 Thermal Information

THERMAL METRIC ⁽¹⁾		OPA1671		UNIT
		DBV (SOT-23)	DCK (SC-70)	
		5 PINS	5 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	187.1	214.7	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	107.4	127.1	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	57.5	60.0	°C/W
Ψ_{JT}	Junction-to-top characterization parameter	33.5	33.4	°C/W
Ψ_{JB}	Junction-to-board characterization parameter	57.1	59.8	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	n/a	n/a	°C/W

- (1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

6.5 Electrical Characteristics

at $V_S = \pm 0.85\text{ V}$ to $\pm 2.75\text{ V}$ ($V_S = 1.7\text{ V}$ to 5.5 V), $T_A = 25^\circ\text{C}$, $R_L = 10\text{ k}\Omega$ connected to $V_S / 2$, $V_{CM} = V_S / 2$, and $V_{OUT} = V_S / 2$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT	
AUDIO PERFORMANCE								
THD+N	Total harmonic distortion + noise	$G = 1$, $f = 1\text{ kHz}$, $V_O = 1\text{ V}_{RMS}$, $V_S = 5.5\text{ V}$		0.00035%				
					-109		dB	
IMD	Intermodulation distortion	$G = 1$, $V_O = 1\text{ V}_{RMS}$, $V_S = 5.5\text{ V}$	SMPTE/DIN Two-Tone, 4:1, (60 Hz and 7 kHz)	0.00158%				
					-96		dB	
				0.0005%				
			CCIF Two-Tone (19 kHz and 20 kHz)		-106		dB	
FREQUENCY RESPONSE								
GBW	Gain-bandwidth product			13			MHz	
SR	Slew rate	4-V step, $G = 1$		5			V/ μs	
t_S	Settling time	T_O 0.1%, 2-V step, $G = 1$		0.75			μs	
		T_O 0.01%, 2-V step, $G = 1$		1				
	Overload recovery time	$V_{IN} \times \text{gain} > V_S$		0.35			μs	
NOISE								
	Input voltage noise	$f = 0.1\text{ Hz}$ to 10 Hz		2.4			μV_{PP}	
e_N	Input voltage noise density	$f = 10\text{ Hz}$		45			$\text{nV}/\sqrt{\text{Hz}}$	
		$f = 1\text{ kHz}$		7				
		$f = 10\text{ kHz}$		4.0				
i_N	Input current noise	$f = 1\text{ kHz}$		4.7			$\text{fA}/\sqrt{\text{Hz}}$	
OFFSET VOLTAGE								
V_{OS}	Input offset voltage	$V_{CM} = (V_+)$				± 1.6	mV	
		$V_{CM} = (V_-)$				± 1.6		
		$T_A = -40^\circ\text{C}$ to 125°C		± 0.25		± 1.25		
dV_{OS}/dT	Input offset voltage drift	$T_A = -40^\circ\text{C}$ to 125°C		± 0.3		± 2.2	$\mu\text{V}/^\circ\text{C}$	
PSRR	Input offset voltage versus power supply	$V_{CM} = (V_-)$		± 30		± 130	$\mu\text{V}/\text{V}$	
INPUT BIAS CURRENT								
I_B	Input bias current			± 10			pA	
I_{OS}	Input offset current			± 10				
INPUT VOLTAGE RANGE								
V_{CM}	Common-mode voltage range			V-		V+	V	
CMRR	Common-mode rejection ratio	$V_S = 1.7\text{ V}$, $(V_-) < V_{CM} < (V_+) - 1.25\text{ V}$		74	91		dB	
		$V_S = 5.5\text{ V}$, $(V_-) < V_{CM} < (V_+) - 1.25\text{ V}$		80	96			
		$V_S = 1.7\text{ V}$, $V_{CM} = 0\text{ V}$ to 1.7 V		60	88			
		$V_S = 5.5\text{ V}$, $V_{CM} = 0\text{ V}$ to 5.5 V		68	102			
INPUT CAPACITANCE								
Z_{ID}	Differential			$10^{13} \parallel 6$			$\text{M}\Omega \parallel \text{pF}$	
Z_{ICM}	Common-mode			$10^{13} \parallel 2.5$			$\text{G}\Omega \parallel \text{pF}$	
OPEN-LOOP GAIN								
A_{OL}	Open-loop voltage gain	$(V_-) + 50\text{ mV} < V_O < (V_+) - 50\text{ mV}$, $R_L = 10\text{ k}\Omega$				97	113	dB
				$T_A = -40^\circ\text{C}$ to 125°C		106		
		$(V_-) + 200\text{ mV} < V_O < (V_+) - 200\text{ mV}$, $R_L = 2\text{ k}\Omega$				97	112	
				$T_A = -40^\circ\text{C}$ to 125°C		105		

Electrical Characteristics (continued)

at $V_S = \pm 0.85\text{ V}$ to $\pm 2.75\text{ V}$ ($V_S = 1.7\text{ V}$ to 5.5 V), $T_A = 25^\circ\text{C}$, $R_L = 10\text{ k}\Omega$ connected to $V_S / 2$, $V_{CM} = V_S / 2$, and $V_{OUT} = V_S / 2$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
OUTPUT						
	Voltage output swing from rail	$V_S = 5.5\text{ V}$, $R_L = 10\text{ k}\Omega$		10	20	mV
I_{SC}	Short-circuit current	Sinking, $V_S = 5.5\text{ V}$		-57		mA
		Sourcing, $V_S = 5.5\text{ V}$		66		
POWER SUPPLY						
I_Q	Quiescent current per amplifier	$I_O = 0\text{ mA}$		0.94	1.3	mA
		$I_O = 0\text{ mA}$, $T_A = -40^\circ\text{C}$ to 125°C			1.4	

6.6 Typical Characteristics

at $T_A = 25^\circ\text{C}$, $V_S = \pm 2.5\text{ V}$, $V_{CM} = V_S / 2$, $R_L = 10\text{ k}\Omega$ connected to $V_S / 2$ (unless otherwise noted)

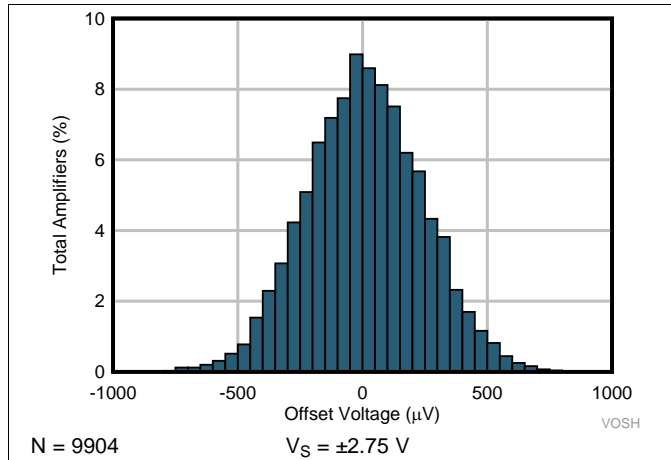


Figure 1. Offset Voltage Production Distribution

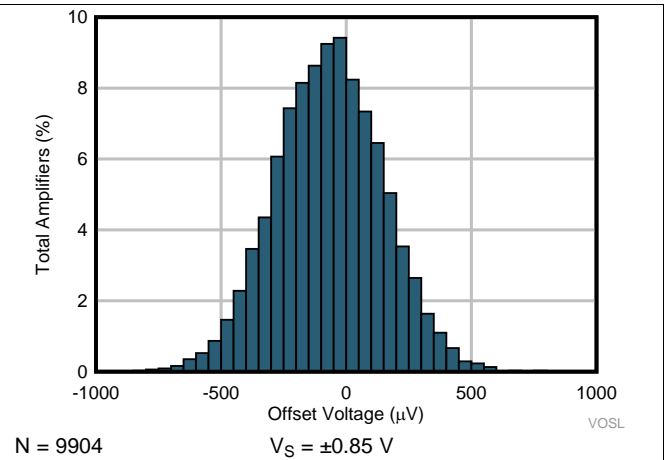


Figure 2. Offset Voltage Production Distribution

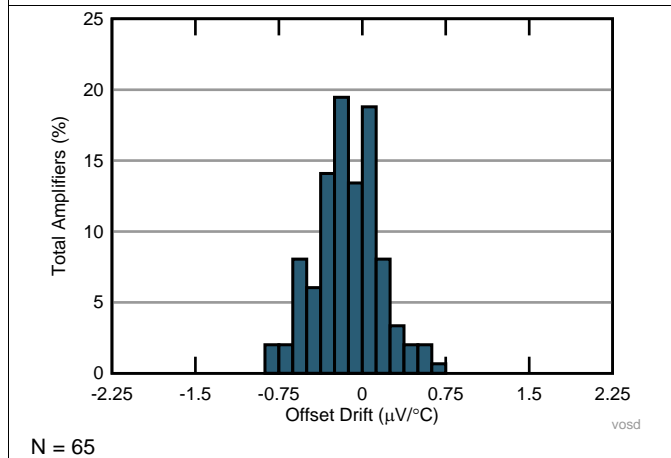


Figure 3. Offset Voltage Drift Distribution

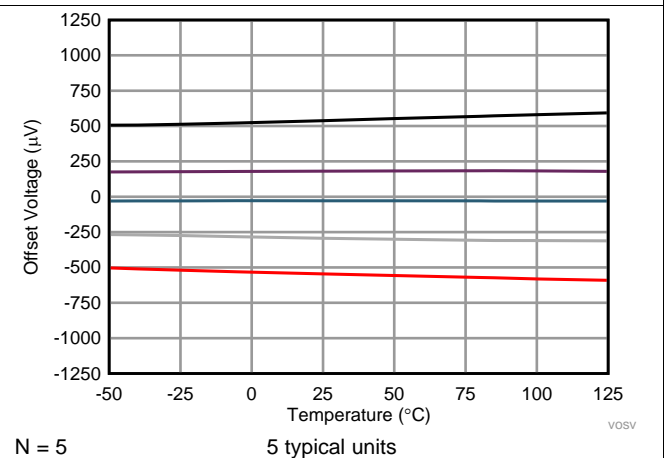


Figure 4. Offset Voltage vs Temperature

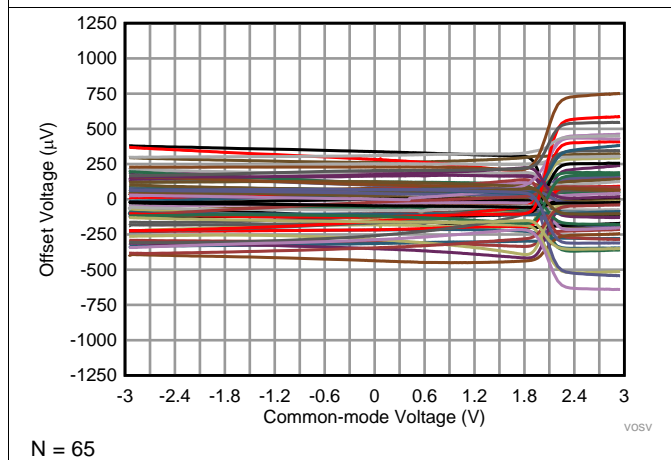


Figure 5. Offset Voltage vs Common Mode Voltage

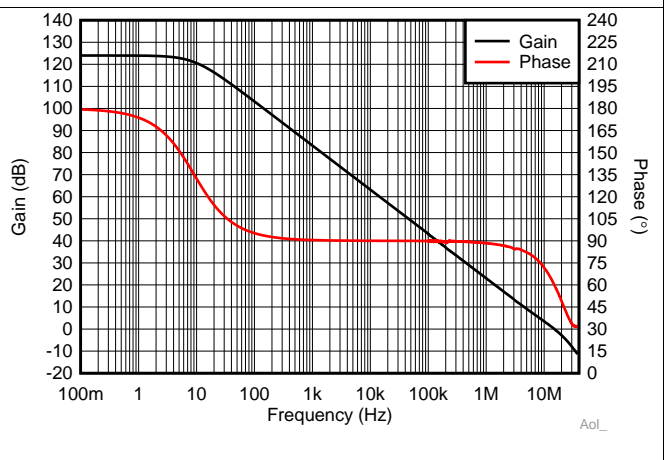


Figure 6. Open-Loop Gain and Phase vs Frequency

Typical Characteristics (continued)

at $T_A = 25^\circ\text{C}$, $V_S = \pm 2.5\text{ V}$, $V_{CM} = V_S / 2$, $R_L = 10\text{ k}\Omega$ connected to $V_S / 2$ (unless otherwise noted)

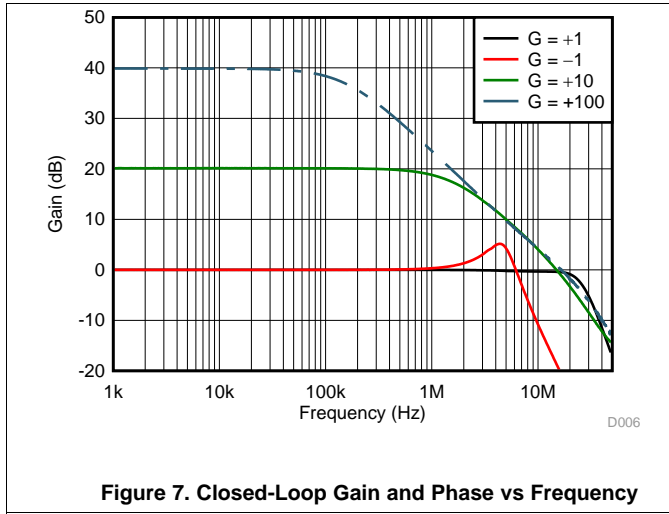


Figure 7. Closed-Loop Gain and Phase vs Frequency

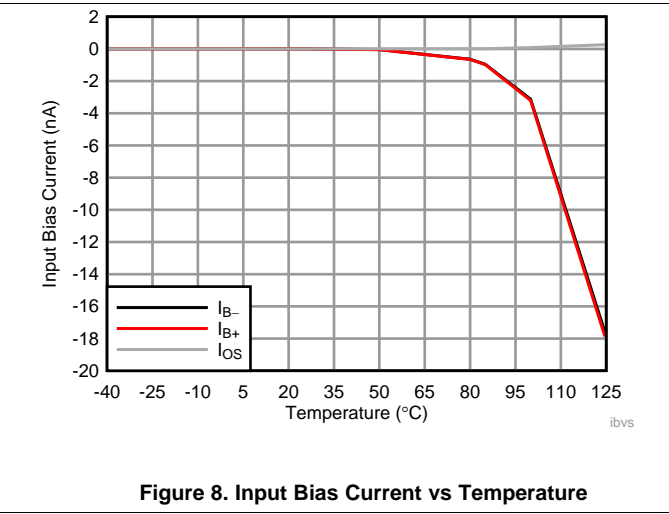


Figure 8. Input Bias Current vs Temperature

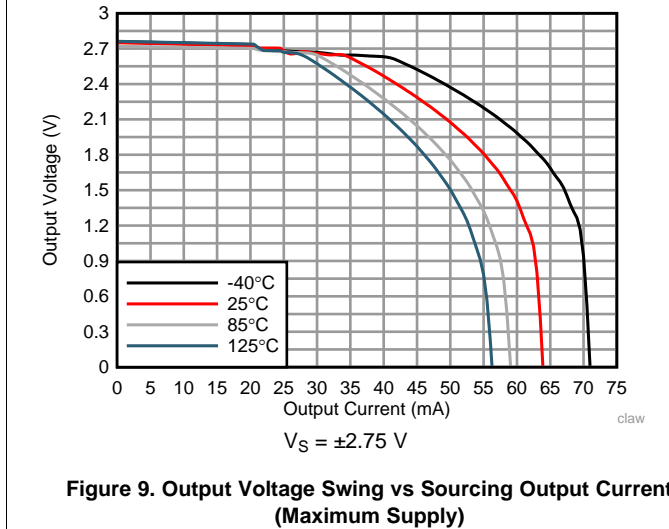


Figure 9. Output Voltage Swing vs Sourcing Output Current (Maximum Supply)

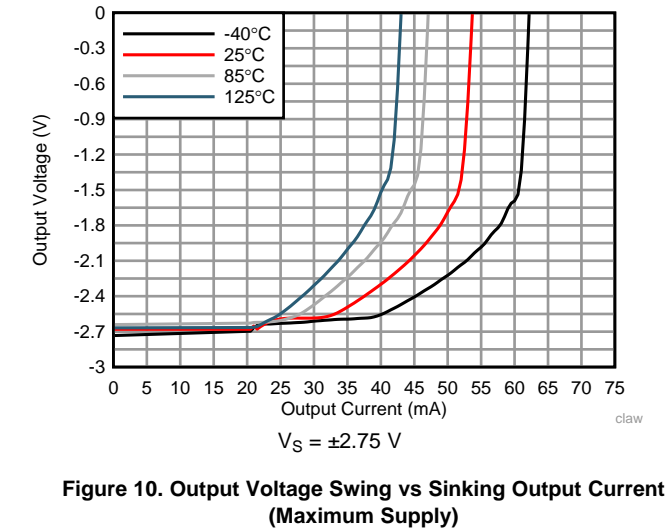


Figure 10. Output Voltage Swing vs Sinking Output Current (Maximum Supply)

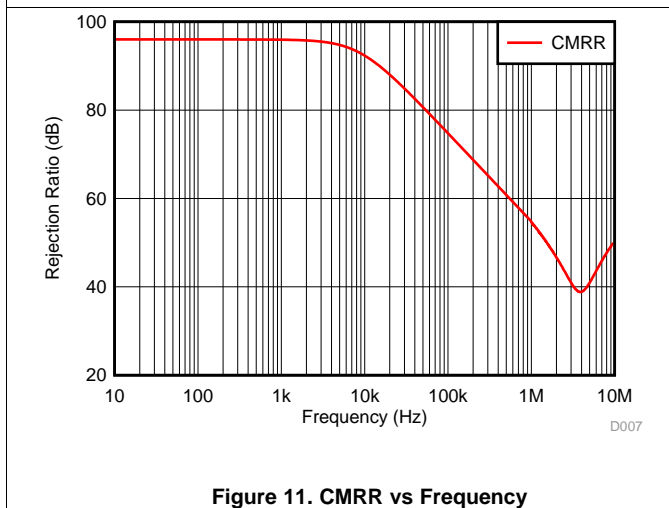


Figure 11. CMRR vs Frequency

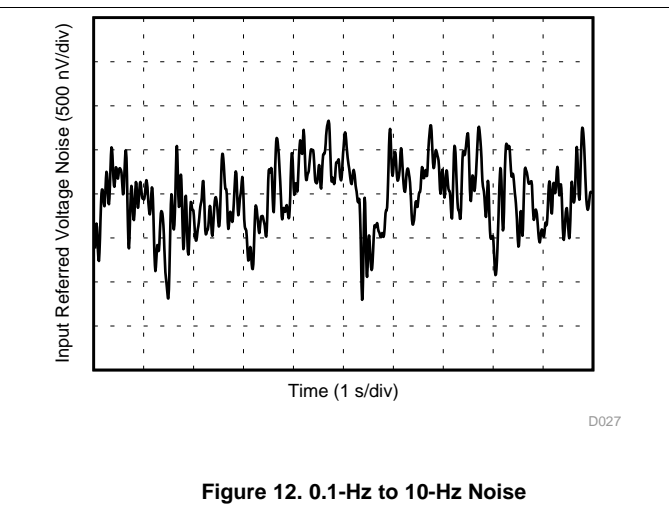
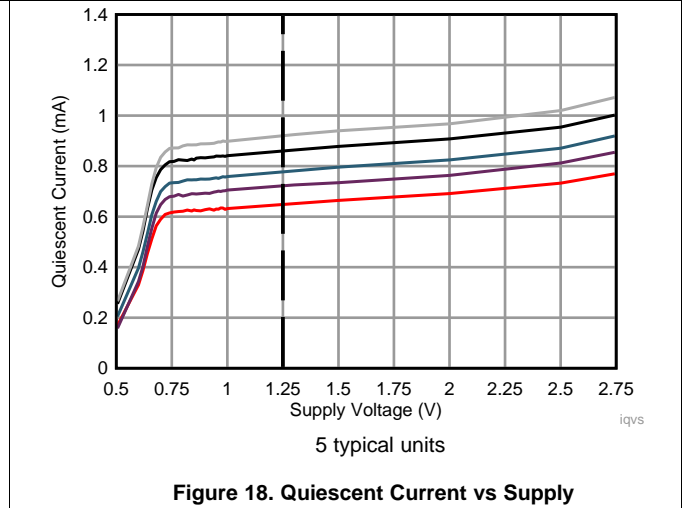
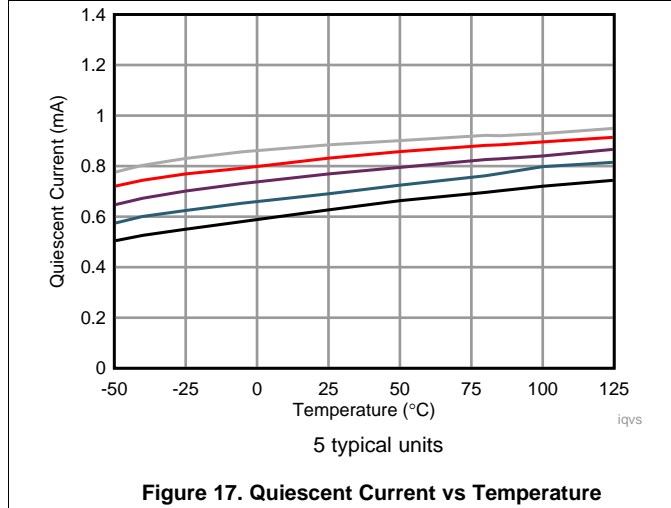
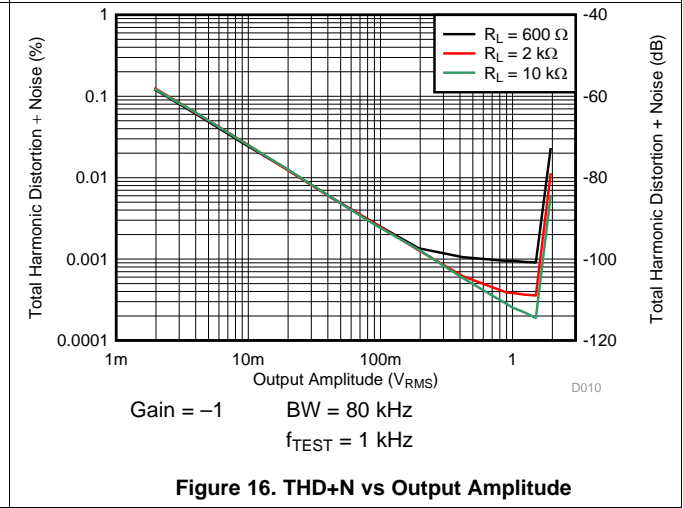
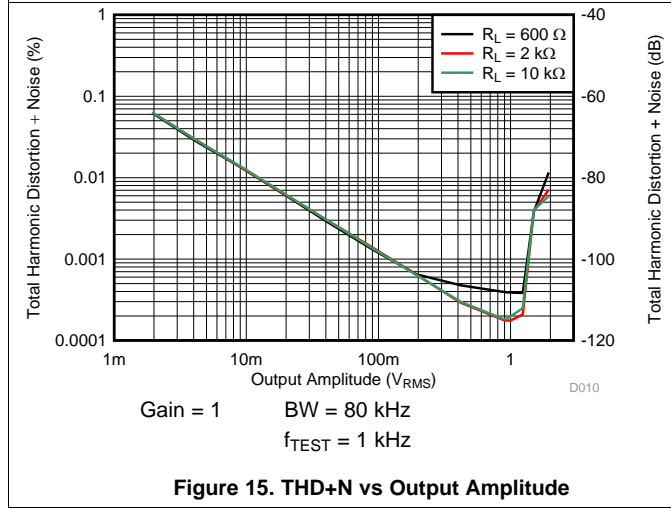
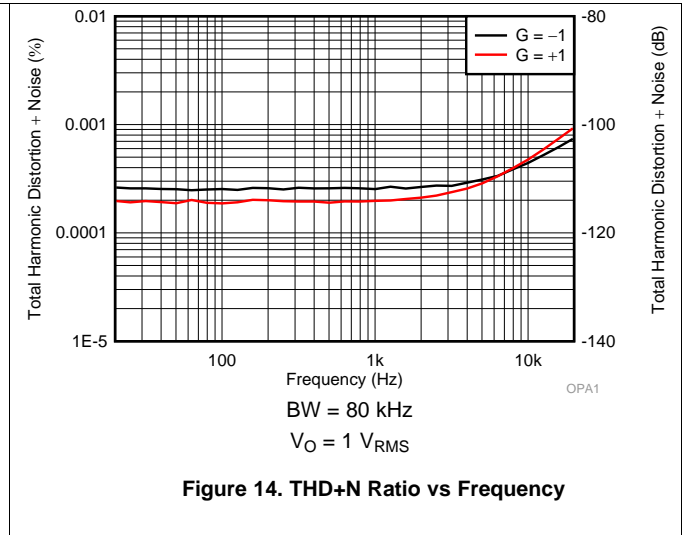
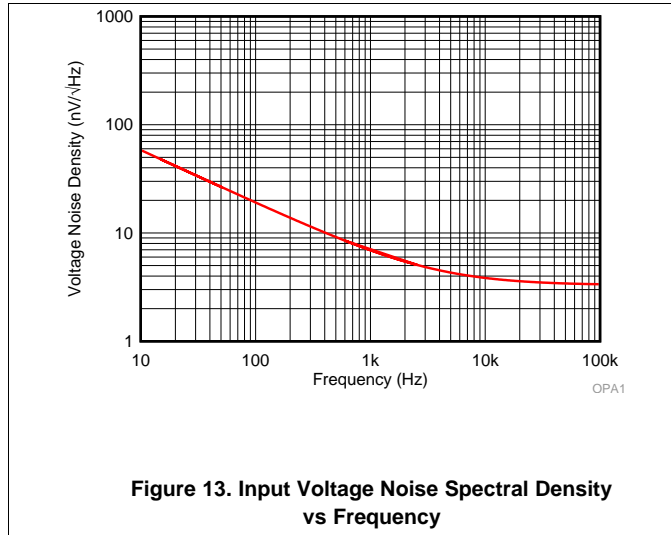


Figure 12. 0.1-Hz to 10-Hz Noise

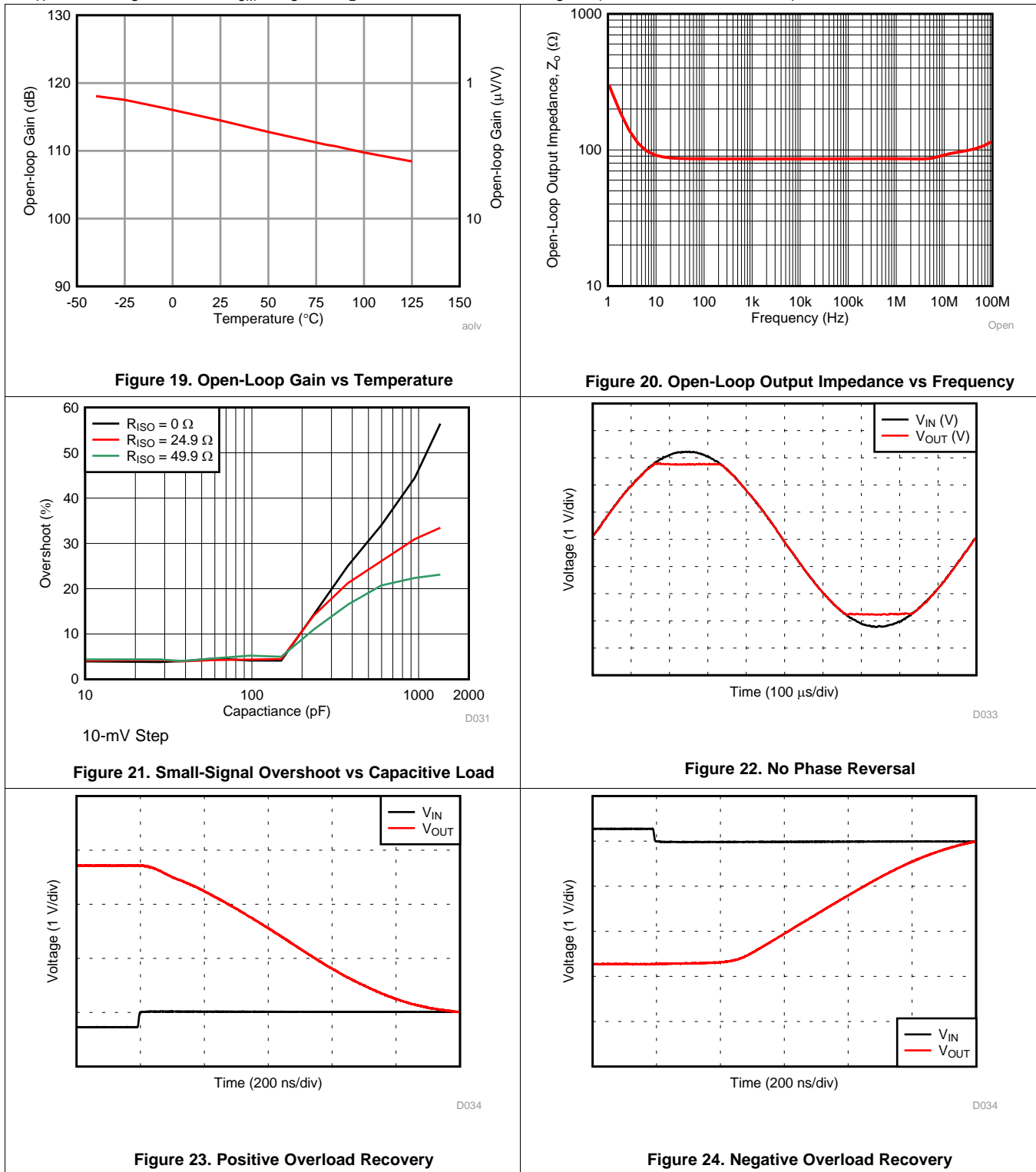
Typical Characteristics (continued)

at $T_A = 25^\circ\text{C}$, $V_S = \pm 2.5\text{ V}$, $V_{CM} = V_S / 2$, $R_L = 10\text{ k}\Omega$ connected to $V_S / 2$ (unless otherwise noted)



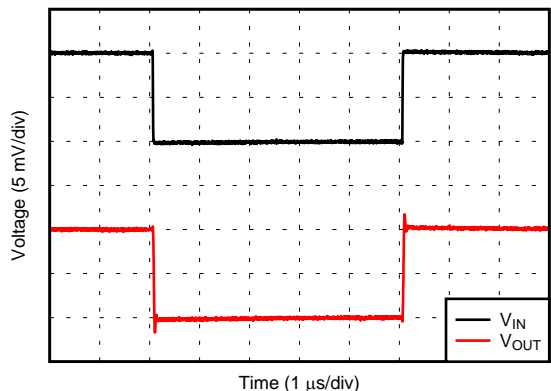
Typical Characteristics (continued)

at $T_A = 25^\circ\text{C}$, $V_S = \pm 2.5\text{ V}$, $V_{CM} = V_S / 2$, $R_L = 10\text{ k}\Omega$ connected to $V_S / 2$ (unless otherwise noted)



Typical Characteristics (continued)

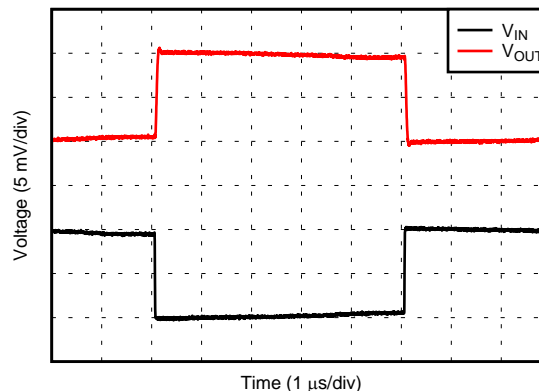
at $T_A = 25^\circ\text{C}$, $V_S = \pm 2.5\text{ V}$, $V_{CM} = V_S / 2$, $R_L = 10\text{ k}\Omega$ connected to $V_S / 2$ (unless otherwise noted)



10-mV step $G = +1$

D035

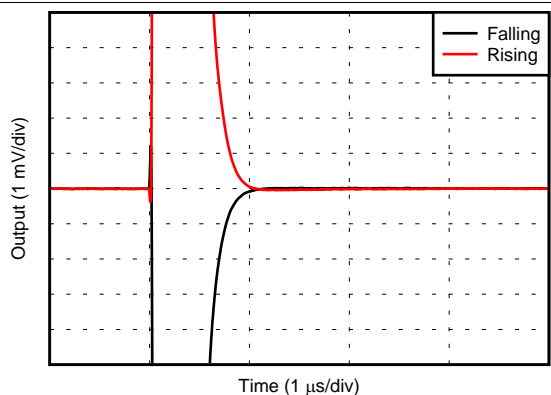
Figure 25. Small-Signal Step Response



10-mV step $G = -1$

D035

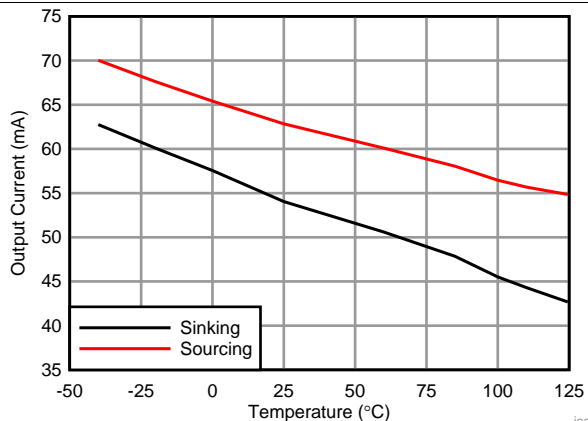
Figure 26. Small-Signal Step Response



2-V Step

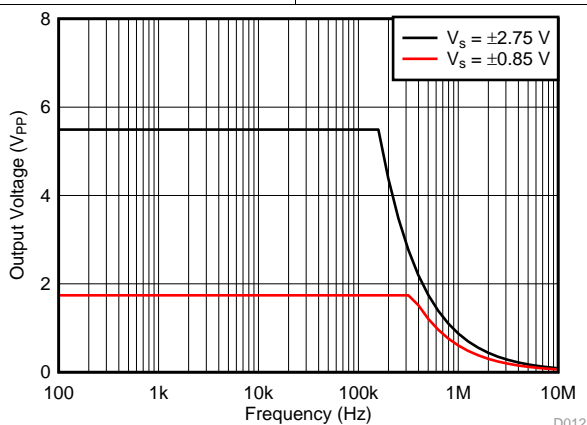
D037

Figure 27. Settling Time



iscv

Figure 28. Short-Circuit Current vs Temperature



D012

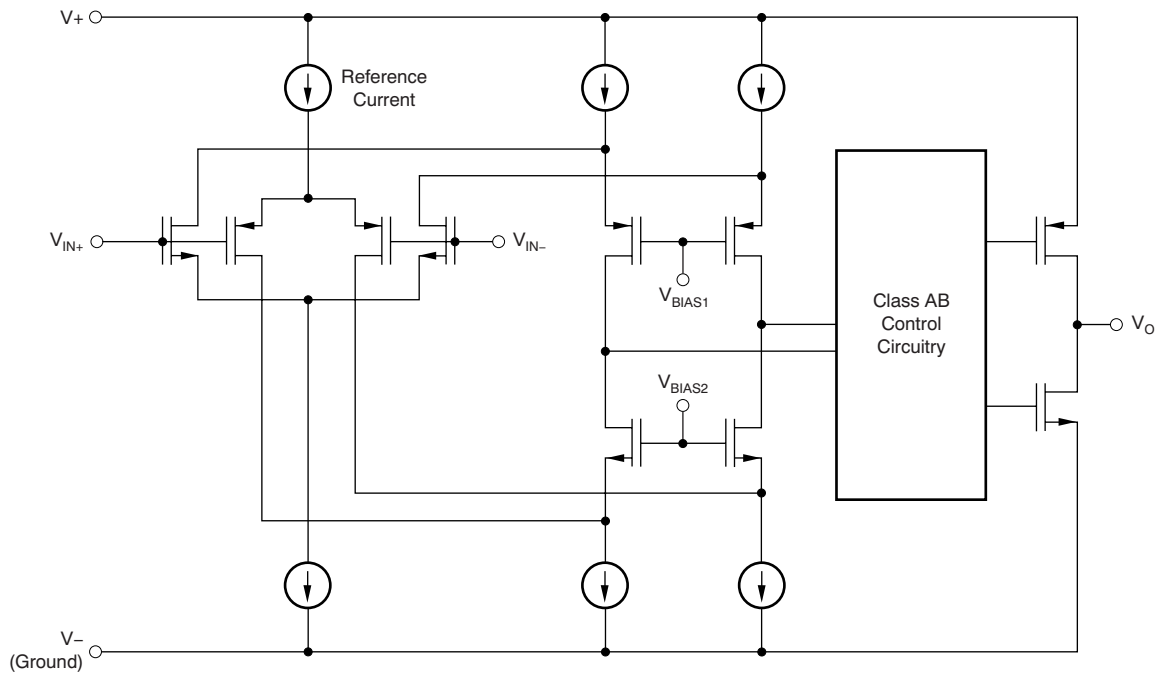
Figure 29. Maximum Output Voltage vs Frequency

7 Detailed Description

7.1 Overview

The OPA1671 is a rail-to-rail input, very low noise operational amplifier (op amp). The OPA1671 operates from 1.7 V to 5.5 V, is unity-gain stable, and is designed for a wide range of audio and general-purpose applications. The OPA1671 strengths also include 13-MHz bandwidth and 4.0-nV/ $\sqrt{\text{Hz}}$ noise spectral density, with very low input bias current (10 pA). These strengths make the OPA1671 a great choice for a preamplifier in microphone circuits, sensor modules and buffering high-fidelity, digital-to-analog converters (DACs).

7.2 Functional Block Diagram



7.3 Feature Description

7.3.1 Operating Voltage

The OPA1671 op amp can be used with single or dual supplies from an operating range of $V_S = 1.7\text{ V}$ ($\pm 0.85\text{ V}$) up to 5.5 V ($\pm 2.75\text{ V}$).

CAUTION

Supply voltages greater than 6 V can permanently damage the device (see [Absolute Maximum Ratings](#))

Key parameters that vary over the supply voltage or temperature range are shown in the [Typical Characteristics](#) section.

7.3.2 Input Bias Current

Typically, input bias current is approximately $\pm 10\text{ pA}$. Input voltages exceeding the power supplies, however, can cause excessive current to flow into or out of the input pins. Momentary voltages greater than the power supply can be tolerated if the input current is limited to 10 mA . This limitation is easily accomplished with an input resistor, as shown in [Figure 30](#).

Unlike many operational amplifiers, there are no diodes connected between the positive and negative input terminals. As a result, differential voltages up to the full supply voltage do not cause any significantly higher current flow into the inputs.

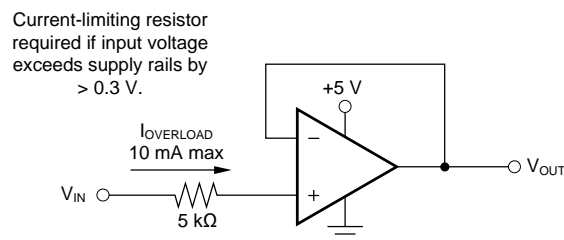


Figure 30. Input Current Protection

7.3.3 Common-Mode Voltage Range

The OPA1671 features true rail-to-rail inputs, allowing full common mode operation from the negative supply voltage to the positive supply voltage. This full common mode operation is achieved with complimentary N-channel and P-channel differential input pairs. The N-channel pair is active for input voltages close to the positive rail, typically $(V+) - 1.25\text{ V}$ to $(V+)$. The P-channel is active for common-mode inputs from $(V-)$ to $(V+) - 1.25\text{ V}$. There is a small transition region, typically from $(V+) - 1.25\text{ V}$ to $(V+) - 1\text{ V}$. In this region, the offset voltage transitions between the P-channel and N-channel offset values. [Figure 5](#) shows the difference between offset in the P and N regions.

Feature Description (continued)

7.3.4 EMI Susceptibility and Input Filtering

Operational amplifiers vary in susceptibility to EMI. If conducted EMI enters the operational amplifier, the dc offset at the amplifier output can shift from its nominal value when EMI is present. This shift is a result of signal rectification associated with the internal semiconductor junctions. Although all operational amplifier pin functions can be affected by EMI, the input pins are likely to be the most susceptible. The OPA1671 operational amplifier incorporates an internal input low-pass filter that reduces the amplifier response to EMI. Both common-mode and differential-mode filtering are provided by the input filter. The filter is designed for a cutoff frequency of approximately 20 MHz (–3 dB), with a rolloff of 20 dB per decade.

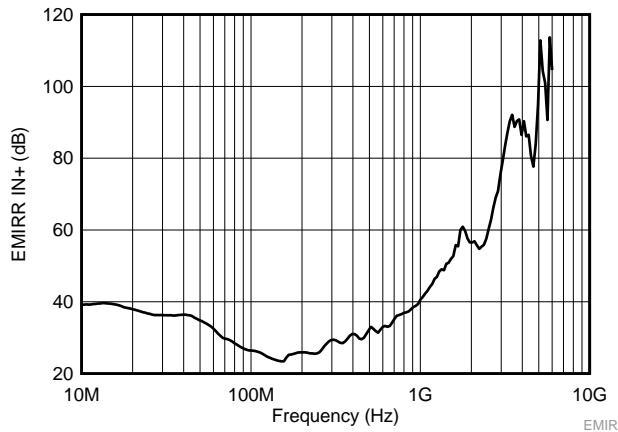


Figure 31. OPA1671 EMIRR vs Frequency

Table 1. OPA1671 EMIRR IN+ for Frequencies of Interest

FREQUENCY	APPLICATION OR ALLOCATION	EMIRR IN+
400 MHz	Mobile radio, mobile satellite, space operation, weather, radar, ultra-high frequency (UHF) applications	30 dB
900 MHz	Global system for mobile communications (GSM) applications, radio communication, navigation, GPS (to 1.6 GHz), GSM, aeronautical mobile, UHF applications	38 dB
1.8 GHz	GSM applications, mobile personal communications, broadband, satellite, L-band (1 GHz to 2 GHz)	60 dB
2.4 GHz	802.11b, 802.11g, 802.11n, Bluetooth®, mobile personal communications, industrial, scientific and medical (ISM) radio band, amateur radio and satellite, S-band (2 GHz to 4 GHz)	59 dB
3.6 GHz	Radiolocation, aero communication and navigation, satellite, mobile, S-band	90 dB
5 GHz	802.11a, 802.11n, aero communication and navigation, mobile communication, space and satellite operation, C-band (4 GHz to 8 GHz)	100 dB

7.4 Device Functional Modes

The OPA1671 has a single functional mode and is operational when the power-supply voltage is greater than 1.7 V (± 0.85 V). The maximum specified power-supply voltage for the OPA1671 is 5.5 V (± 2.75 V).

8 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

The OPA1671 is a low-noise, rail-to-rail input and output operational amplifier specifically designed for portable applications. The device operates from 1.7 V to 5.5 V, is unity-gain stable, and suitable for a wide range of audio and general-purpose applications. The class AB output stage is capable of driving $\leq 10\text{-k}\Omega$ loads connected to any point between $V+$ and ground. The input common-mode voltage range includes both rails, and allows the OPA1671 device to be used in virtually any single-supply application. Rail-to-rail input and output swing significantly increases dynamic range, especially in low-supply applications, and makes the device a great choice for driving sampling analog-to-digital converters (ADCs).

8.1.1 Capacitive Loads

The dynamic characteristics of the OPA1671 amplifiers are optimized for commonly encountered gains, loads, and operating conditions. The combination of low closed-loop gain and high capacitive loads decreases the phase margin of the amplifier and can lead to gain peaking or oscillations. As a result, heavier capacitive loads must be isolated from the output. Add a small resistor (for example, $R_S = 50\ \Omega$) in series with the output to isolate heavier capacitive loads.

8.1.2 Noise Performance

Figure 31 shows the total circuit noise for varying source impedances with the operational amplifier in a unity-gain configuration (with no feedback resistor network and therefore no additional noise contributions). The op amp itself contributes a voltage noise component and a current noise component. The voltage noise is commonly modeled as a time-varying component of the offset voltage. The current noise is modeled as the time-varying component of the input bias current and reacts with the source resistance to create a voltage component of noise. For a CMOS-input device, the noise resulting from the input current is negligible; therefore, the total noise is dominated by the voltage noise of the OPA1671 at low source resistance, and the resistor noise $> 1\ \text{k}\Omega$.

Figure 31 shows the calculation of the total circuit noise, with these parameters:

- e_n = voltage noise
- R_S = source impedance
- k = Boltzmann's constant = $1.38 \times 10^{-23}\ \text{J/K}$
- T = temperature in kelvins (K)

For more details on calculating noise, see [Basic Noise Calculations](#).

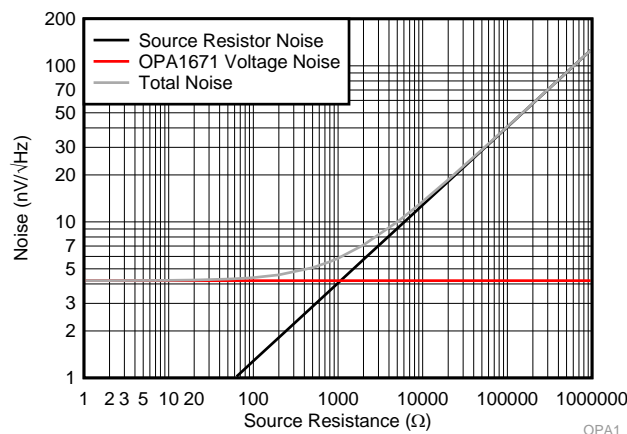


Figure 32. Noise Performance of the OPA1671 in a Unity-Gain Buffer Configuration

Application Information (continued)

8.1.3 Basic Noise Calculations

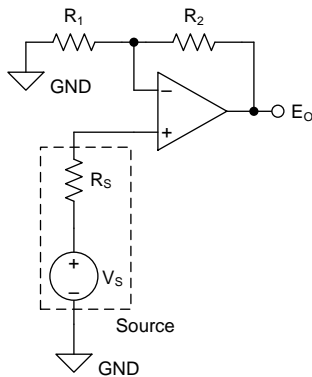
Low-noise circuit design requires careful analysis of all noise sources. External noise sources can dominate in many cases; consider the effect of source resistance on overall op amp noise performance. Total noise of the circuit is the root-sum-square combination of all noise components.

The resistive portion of the source impedance produces thermal noise proportional to the square root of the resistance. This function is plotted in [Figure 31](#). The source impedance is typically fixed; consequently, select the op amp and the feedback resistors to minimize the respective contributions to the total noise.

[Figure 33](#) shows noninverting (A) and inverting (B) op amp circuit configurations with gain. In circuit configurations with gain, the feedback network resistors contribute noise. In general, the current noise of the op amp reacts with the feedback resistors to create additional noise components.

The selected feedback resistor values make these noise sources negligible. Low impedance feedback resistors load the output of the amplifier. The equations for total noise are shown for both configurations.

(A) Noise in Noninverting Gain Configuration



Noise at the output is given as E_O , where

$$(1) \quad E_O = \left(1 + \frac{R_2}{R_1}\right) \cdot \sqrt{(e_S)^2 + (e_N)^2 + (e_{R_1 \parallel R_2})^2 + (i_N \cdot R_S)^2 + \left(i_N \cdot \left[\frac{R_1 \cdot R_2}{R_1 + R_2}\right]\right)^2} \quad [V_{RMS}]$$

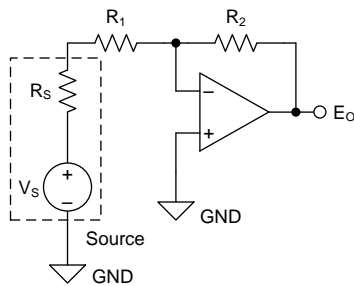
$$(2) \quad e_S = \sqrt{4 \cdot k_B \cdot T(K) \cdot R_S} \quad \left[\frac{V}{\sqrt{Hz}}\right] \quad \text{Thermal noise of } R_S$$

$$(3) \quad e_{R_1 \parallel R_2} = \sqrt{4 \cdot k_B \cdot T(K) \cdot \left[\frac{R_1 \cdot R_2}{R_1 + R_2}\right]} \quad \left[\frac{V}{\sqrt{Hz}}\right] \quad \text{Thermal noise of } R_1 \parallel R_2$$

$$(4) \quad k_B = 1.38065 \cdot 10^{-23} \quad \left[\frac{J}{K}\right] \quad \text{Boltzmann Constant}$$

$$(5) \quad T(K) = 237.15 + T(^{\circ}C) \quad [K] \quad \text{Temperature in kelvins}$$

(B) Noise in Inverting Gain Configuration



Noise at the output is given as E_O , where

$$(6) \quad E_O = \left(1 + \frac{R_2}{R_S + R_1}\right) \cdot \sqrt{(e_N)^2 + (e_{R_1 + R_S \parallel R_2})^2 + \left(i_N \cdot \left[\frac{(R_S + R_1) \cdot R_2}{R_S + R_1 + R_2}\right]\right)^2} \quad [V_{RMS}]$$

$$(7) \quad e_{R_1 + R_S \parallel R_2} = \sqrt{4 \cdot k_B \cdot T(K) \cdot \left[\frac{(R_S + R_1) \cdot R_2}{R_S + R_1 + R_2}\right]} \quad \left[\frac{V}{\sqrt{Hz}}\right] \quad \text{Thermal noise of } (R_1 + R_S) \parallel R_2$$

$$(8) \quad k_B = 1.38065 \cdot 10^{-23} \quad \left[\frac{J}{K}\right] \quad \text{Boltzmann Constant}$$

$$(9) \quad T(K) = 237.15 + T(^{\circ}C) \quad [K] \quad \text{Temperature in kelvins}$$

Copyright © 2017, Texas Instruments Incorporated

- (1) e_N is the voltage noise of the amplifier. For the OPA1671 series of operational amplifiers, $e_N = 4.0 \text{ nV}/\sqrt{\text{Hz}}$ at 10 kHz.
- (2) i_N is the current noise of the amplifier. For the OPA1671 series of operational amplifiers, $i_N = 4.5 \text{ fA}/\sqrt{\text{Hz}}$ at 1 kHz.
- (3) For additional resources on noise calculations, see [TI's Precision Labs Series](#).

Figure 33. Noise Calculation in Gain Configurations

8.2 Typical Application

This design uses an OPA1671 as a preamplifier for an electret microphone. Electret microphone types are common in many audio applications of varying performance levels. The OPA1671 offers very low noise in a tiny package, and is designed for use in electret preamplifier circuits.

Figure 34 shows the solution.

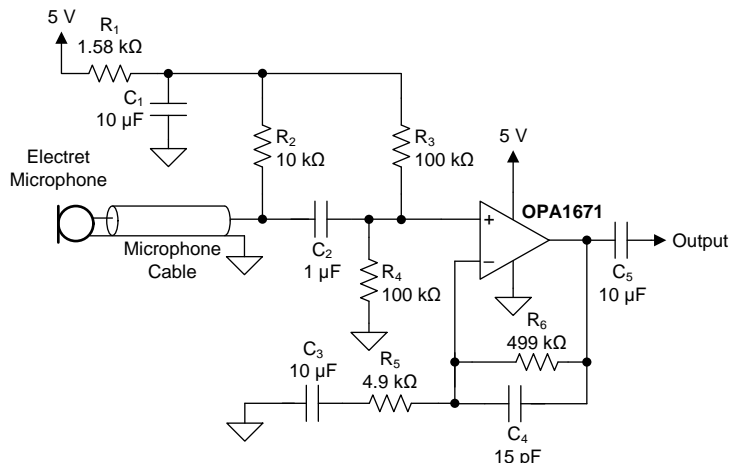


Figure 34. Electret Preamplifier Schematic

8.2.1 Design Requirements

This solution has the following requirements:

- Supply voltage: 5 V
- Gain: 100 V/V
- Frequency response: 3 dB from 20 Hz to 20 kHz
- Output: 2.5 V ±1 V
- Output noise density: < 1 μV/√Hz at 10 kHz

Typical Application (continued)

8.2.2 Detailed Design Procedure

The preamplifier circuit uses a noninverting gain configuration to allow for high input impedance, with independent gain-setting resistor values. DC bypass is accomplished with C_2 and C_3 , with the low frequency poles set by C_2 , R_4 , C_3 and R_5 ; see [Equation 1](#) and [Equation 2](#).

$$p_{L1} = \frac{1}{2\pi \cdot (R_3 \parallel R_4) \cdot C_2} = 3.18 \text{ Hz} \tag{1}$$

$$p_{L2} = \frac{1}{2\pi \cdot R_5 \cdot C_2} = 3.23 \text{ Hz} \tag{2}$$

The filter cutoff frequency is determined by a higher frequency pole, set by R_5 and C_4 .

$$p_H = \frac{1}{2\pi \cdot R_6 \cdot C_4} = 21.3 \text{ kHz} \tag{3}$$

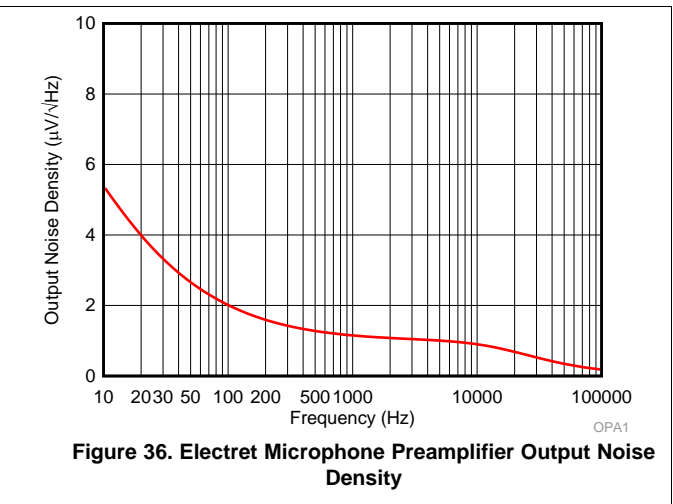
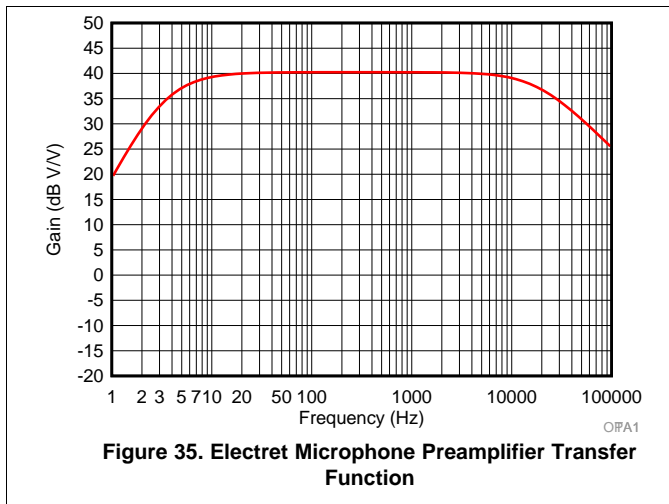
The gain of the circuit in the passband is set by R_5 and R_6 .

$$A(V/V) = \frac{R_6}{R_5} = 100 (40 \text{ dB}) \tag{4}$$

The output noise of the circuit (ignoring the electret microphone intrinsic noise and impedance) is the RSS average noise contribution from R_5 and the input voltage noise of OPA1671. R_5 was selected for minimal noise contribution without requiring a dc blocking cap. (C_3) larger than $10 \mu\text{F}$. See [Equation 5](#) for the output noise density calculation at 10 kHz.

$$e_{N_OUT} = \text{Input Referred Noise} \cdot \text{Gain} = \sqrt{(4kTR_5)^2 + V_{N_10k}^2} \cdot 100 = 0.96 \mu\text{V}/\sqrt{\text{Hz}} \tag{5}$$

8.2.3 Application Curves



9 Power Supply Recommendations

The OPA1671 device is specified for operation from 1.7 V to 5.5 V (± 0.85 V to ± 2.75 V).

10 Layout

10.1 Layout Guidelines

Paying attention to good layout practice is always recommended. Keep traces short and, when possible, use a printed-circuit board (PCB) ground plane with surface-mount components placed as close to the device pins as possible. Place a 0.1- μ F capacitor closely across the supply pins. These guidelines must be applied throughout the analog circuit to improve performance and provide benefits such as reducing the electromagnetic interference (EMI) susceptibility.

10.2 Layout Example

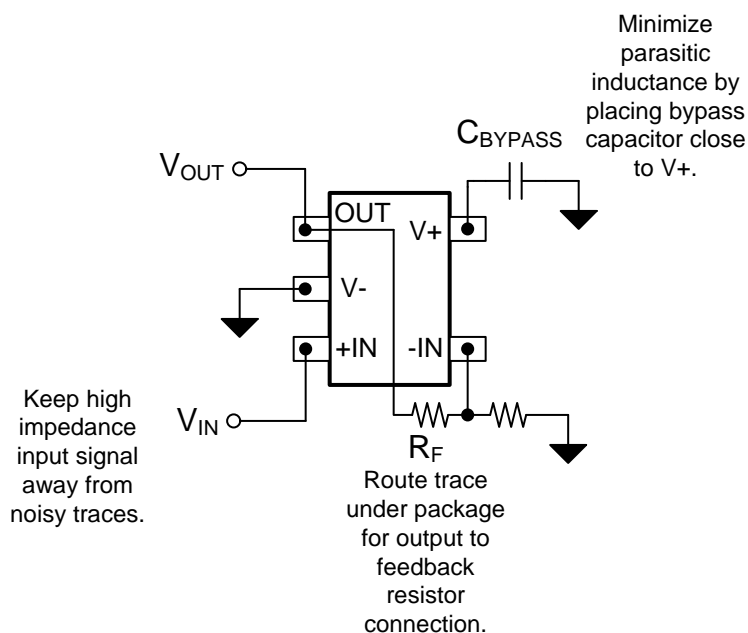


Figure 37. OPA1671 Layout Example

11 Device and Documentation Support

11.1 Device Support

11.1.1 Development Support

11.1.1.1 TINA-TI™ (Free Software Download)

TINA-TI™ is a simple, powerful, and easy-to-use circuit simulation program based on a SPICE engine. TINA-TI™ is a free, fully-functional version of the TINA™ software, preloaded with a library of macromodels in addition to a range of both passive and active models. TINA-TI™ provides all the conventional dc, transient, and frequency domain analysis of SPICE, as well as additional design capabilities.

Available as a [free download](#) from the Analog eLab Design Center, TINA-TI™ offers extensive post-processing capability that allows users to format results in a variety of ways. Virtual instruments offer the ability to select input waveforms and probe circuit nodes, voltages, and waveforms, creating a dynamic quick-start tool.

NOTE

These files require that either the TINA software (from DesignSoft™) or TINA-TI™ software be installed. Download the free TINA-TI™ software from the [TINA-TI™ folder](#).

11.2 Documentation Support

11.2.1 Related Documentation

For related documentation see the following:

- Texas Instruments, [Circuit Board Layout Techniques](#)
- Texas Instruments, [Analog Engineer's Circuit Cookbook](#)

11.3 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

11.4 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

TI E2E™ Online Community *TI's Engineer-to-Engineer (E2E) Community*. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

11.5 Trademarks

TINA-TI, E2E are trademarks of Texas Instruments.
Bluetooth is a registered trademark of Bluetooth SIG, Inc.
TINA, DesignSoft are trademarks of DesignSoft, Inc.
All other trademarks are the property of their respective owners.

11.6 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

11.7 Glossary

[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical packaging and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
OPA1671IDBVR	ACTIVE	SOT-23	DBV	5	3000	RoHS & Green	NIPDAU SN	Level-2-260C-1 YEAR	-40 to 125	1X6T	Samples
OPA1671IDBVT	ACTIVE	SOT-23	DBV	5	250	RoHS & Green	NIPDAU SN	Level-2-260C-1 YEAR	-40 to 125	1X6T	Samples
OPA1671IDCKR	ACTIVE	SC70	DCK	5	3000	RoHS & Green	NIPDAU SN	Level-2-260C-1 YEAR	-40 to 125	1D3	Samples
OPA1671IDCKT	ACTIVE	SC70	DCK	5	250	RoHS & Green	NIPDAU SN	Level-2-260C-1 YEAR	-40 to 125	1D3	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSELETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "-" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer:The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and

continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
OPA1671IDBVR	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
OPA1671IDBVR	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
OPA1671IDBVT	SOT-23	DBV	5	250	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
OPA1671IDBVT	SOT-23	DBV	5	250	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
OPA1671IDCKR	SC70	DCK	5	3000	180.0	8.4	2.3	2.5	1.2	4.0	8.0	Q3
OPA1671IDCKT	SC70	DCK	5	250	180.0	8.4	2.3	2.5	1.2	4.0	8.0	Q3

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
OPA1671IDBVR	SOT-23	DBV	5	3000	210.0	185.0	35.0
OPA1671IDBVR	SOT-23	DBV	5	3000	210.0	185.0	35.0
OPA1671IDBVT	SOT-23	DBV	5	250	210.0	185.0	35.0
OPA1671IDBVT	SOT-23	DBV	5	250	210.0	185.0	35.0
OPA1671IDCKR	SC70	DCK	5	3000	210.0	185.0	35.0
OPA1671IDCKT	SC70	DCK	5	250	210.0	185.0	35.0

EXAMPLE BOARD LAYOUT

DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:15X



SOLDER MASK DETAILS

4214839/K 08/2024

NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:15X

4214839/K 08/2024

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

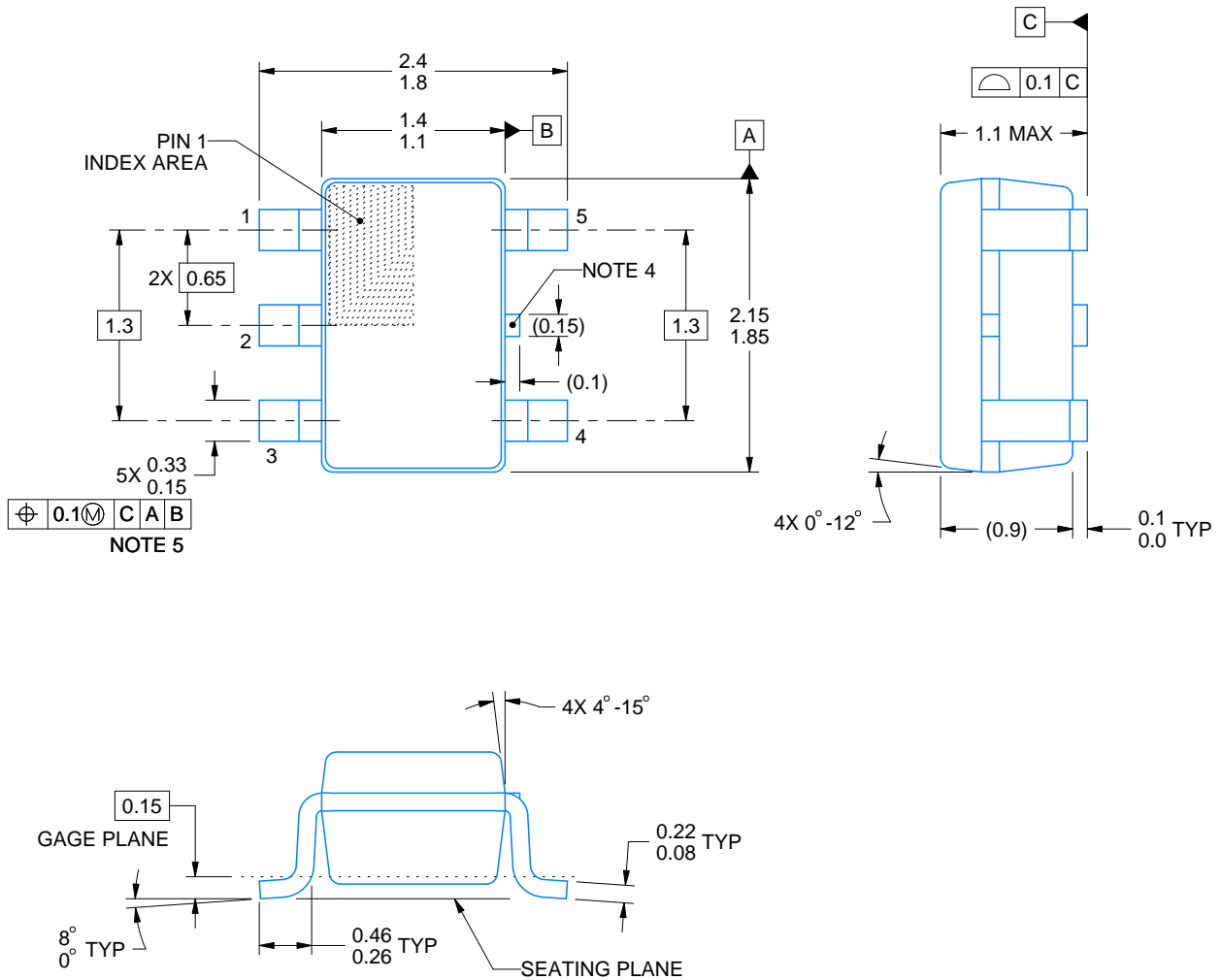
DCK0005A



PACKAGE OUTLINE

SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR



4214834/G 11/2024

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Reference JEDEC MO-203.
4. Support pin may differ or may not be present.
5. Lead width does not comply with JEDEC.
6. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25mm per side

EXAMPLE BOARD LAYOUT

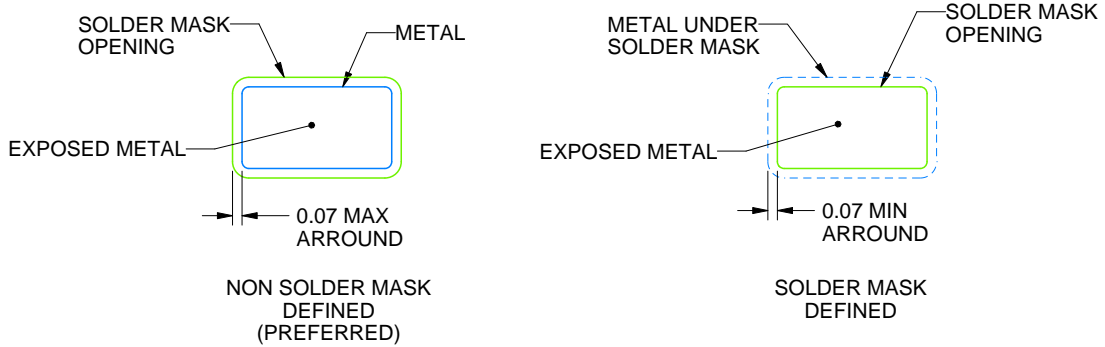
DCK0005A

SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:18X



SOLDER MASK DETAILS

4214834/G 11/2024

NOTES: (continued)

- 7. Publication IPC-7351 may have alternate designs.
- 8. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DCK0005A

SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR



SOLDER PASTE EXAMPLE
BASED ON 0.125 THICK STENCIL
SCALE:18X

4214834/G 11/2024

NOTES: (continued)

9. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
10. Board assembly site may have different recommendations for stencil design.

IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to [TI's Terms of Sale](#) or other applicable terms available either on [ti.com](https://www.ti.com) or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265

Copyright © 2025, Texas Instruments Incorporated